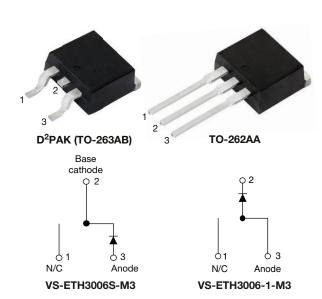


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# Hyperfast Rectifier, 30 A FRED Pt®



PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub>	30 A					
V <sub>R</sub>	600 V					
V <sub>F</sub> at I <sub>F</sub>	1.4 V					
t <sub>rr</sub> (typ.)	27 ns					
T <sub>J</sub> max.	175 °C					
Package	D <sup>2</sup> PAK (TO-263AB), TO-262AA					
Circuit configuration	Single					

#### **FEATURES**

- Hyperfast recovery time
- Low forward voltage drop
- 175 °C operating junction temperature
- · Low leakage current



COMPLIANT

HALOGEN

- Designed and qualified according to JEDEC®-JESD 47
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

#### **DESCRIPTION/APPLICATIONS**

Hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC Boost stage in the AC/DC section of SMPS, inverters or as freewheeling diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS		
Repetitive peak reverse voltage	$V_{RRM}$		600	V		
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 95 °C	30	۸		
Non-repetitive peak surge current	I <sub>FSM</sub>	T <sub>C</sub> = 25 °C	180	7 A		
Operating junction and storage temperatures	T <sub>J</sub> , T <sub>Stg</sub>		-65 to +175	°C		

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)								
PARAMETER	RAMETER SYMBOL TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	Ι <sub>R</sub> = 100 μΑ	600	-	-			
Forward voltage	V	I <sub>F</sub> = 30 A	-	2.0	2.65	V		
	V <sub>F</sub>	I <sub>F</sub> = 30 A, T <sub>J</sub> = 150 °C	-	1.4	1.8			
Reverse leakage current		$V_R = V_R$ rated	-	0.02	30			
neverse leakage current	I <sub>R</sub>	$T_J = 150 ^{\circ}\text{C},  V_R = V_R  \text{rated}$	-	50	300	μΑ		
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 600 V	-	20	-	pF		
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body	-	8.0	-	nΗ		



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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST (	CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Reverse recovery time		$I_F = 1 A, dI_F/dt = 50$	$I_F = 1 \text{ A}, dI_F/dt = 50 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$			35			
	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	26	-	ns		
		T <sub>J</sub> = 125 °C	l <sub>F</sub> = 30 A dl <sub>F</sub> /dt = 200 A/μs V <sub>B</sub> = 200 V	-	70	-			
Dook room ourrent	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C		-	3.5	-	۸		
Peak recovery current		T <sub>J</sub> = 125 °C		-	7.6	-	A		
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	50	-	nC		
		T <sub>J</sub> = 125 °C		-	280	-	110		

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER SYMBOL TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS		
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-65	-	175	°C	
Thermal resistance, junction-to-case	R <sub>thJC</sub>	R <sub>thJC</sub>		0.95	1.4	°C/W	
Thermal resistance, junction-to-ambient	R <sub>thJA</sub>	R <sub>thJA</sub> Typical socket mount		-	70		
Thermal resistance, case-to-heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth, and greased	-	0.5	-		
Woight			-	2.0	-	g	
Weight			-	0.07	-	OZ.	
Mounting torque			6 (5)	-	12 (10)	kgf · cm (lbf · in)	
Morting device		Case style D <sup>2</sup> PAK (TO-263AB)	ETH3006S				
Marking device		Case style TO-262AA	ETH3006-1				

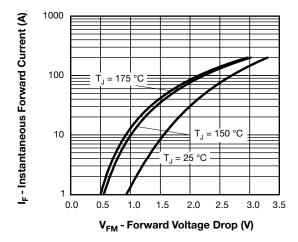


Fig. 1 - Typical Forward Voltage Drop Characteristics

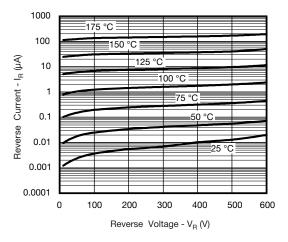


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

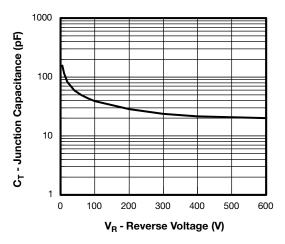


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

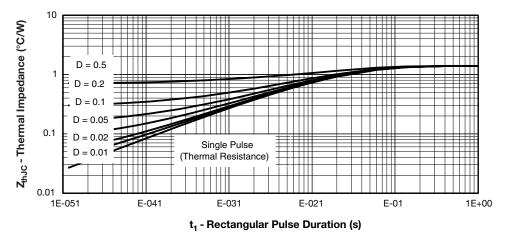


Fig. 4 - Max. Thermal Impedance Z<sub>thJC</sub> Characteristics

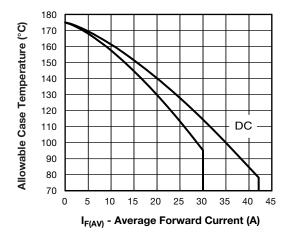


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

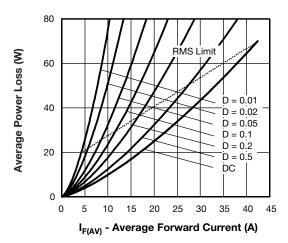
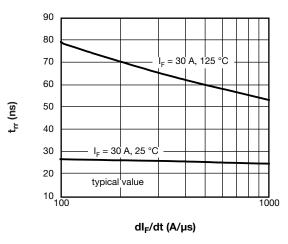


Fig. 6 - Forward Power Loss Characteristics

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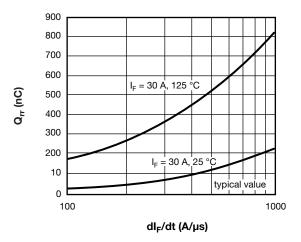
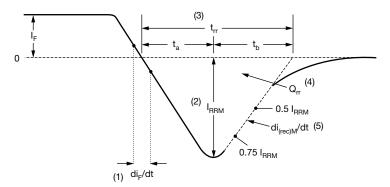


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt



- (1) di<sub>F</sub>/dt rate of change of current through zero crossing
- (2)  $I_{RRM}$  peak reverse recovery current
- (3)  $\rm t_{rr}$  reverse recovery time measured from zero crossing point of negative going  $\rm I_F$  to point where a line passing through 0.75  $\rm I_{RRM}$  and 0.50  $\rm I_{RRM}$  extrapolated to zero current.
- (4)  $\boldsymbol{Q}_{rr}$  area under curve defined by  $\boldsymbol{t}_{rr}$  and  $\boldsymbol{I}_{RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

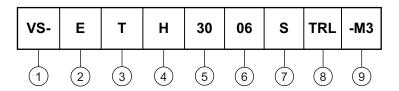
(5) di<sub>(rec)M</sub>/dt - peak rate of change of current during t<sub>h</sub> portion of t<sub>rr</sub>

Fig. 9 - Reverse Recovery Waveform and Definitions



### **ORDERING INFORMATION TABLE**

**Device code** 



1 - Vishay Semiconductors product

2 - Circuit configuration

E = single

3 - T = TO-220

4 - H = hyperfast recovery time

5 - Current code (30 = 30 A)

6 - Voltage code (06 = 600 V)

- • S =  $D^2PAK$  (TO-263AB)

- • -1 = TO-262AA

None = tube (50 pieces)

- • TRL = tape and reel (left oriented, for D<sup>2</sup>PAK (TO-263AB) package)

- • TRR = tape and reel (right oriented, for D<sup>2</sup>PAK (TO-263AB) package)

9 - -M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-ETH3006S-M3	50	1000	Antistatic plastic tube				
VS-ETH3006-1-M3	50	1000	Antistatic plastic tube				
VS-ETH3006STRR-M3	800	800	13" diameter reel				
VS-ETH3006STRL-M3	800	800	13" diameter reel				

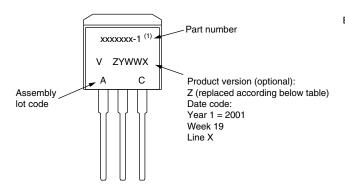
LINKS TO RELATED DOCUMENTS					
Dimensions	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?96164			
Differsions	TO-262AA	www.vishay.com/doc?96165			
Part marking information	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?95444			
Fart marking imormation	TO-262AA	www.vishay.com/doc?95443			
Packaging information	D <sup>2</sup> PAK (TO-263AB)	www.vishay.com/doc?96424			



# **Part Marking Information**

## Vishay Semiconductors

## **TO-262**



Example: This is a xxxxxxx-1 <sup>(1)</sup> with assembly lot code AC, assembled on WW 19, 2001

in the assembly line "X"

#### Note

(1) If part number contain "H" as last digit, product is AEC-Q101 qualified

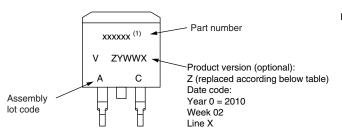
ENVIRONMENTAL NAMING CODE (Z)	PRODUCT DEFINITION
A	Termination lead (Pb)-free
В	Totally lead (Pb)-free
E	RoHS-compliant and termination lead (Pb)-free
F	RoHS-compliant and totally lead (Pb)-free
М	Halogen-free, RoHS-compliant and termination lead (Pb)-free
N	Halogen-free, RoHS-compliant and totally lead (Pb)-free
G	Green



# **Part Marking Information**

Vishay Semiconductors

## D<sup>2</sup>PAK



Example: This is a xxxxxx <sup>(1)</sup> with assembly lot code AC, assembled on WW 02, 2010

#### Note

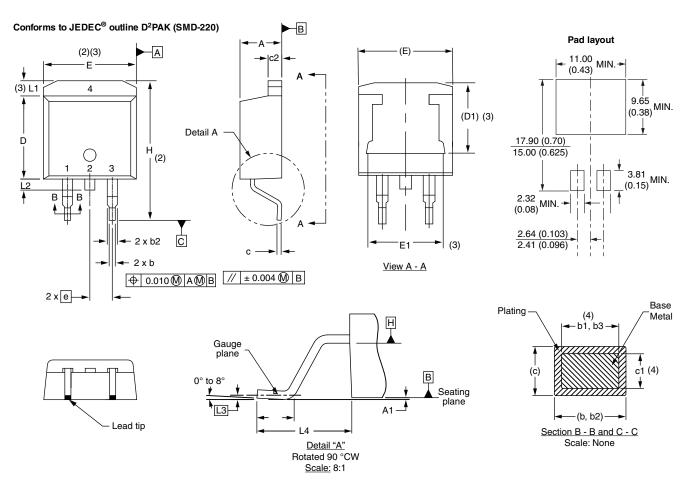
(1) If part number contain "H" as last digit, product is AEC-Q101 qualified

ENVIRONMENTAL NAMING CODE (Z)	PRODUCT DEFINITION		
А	Termination lead (Pb)-free		
В	Totally lead (Pb)-free		
E	RoHS-compliant and termination lead (Pb)-free		
F	RoHS-compliant and totally lead (Pb)-free		
M	Halogen-free, RoHS-compliant, and termination lead (Pb)-free		
N	Halogen-free, RoHS-compliant, and totally lead (Pb)-free		
G Green			



## D<sup>2</sup>PAK

### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIM	IETERS	INCHES		NOTES	NOTES SYMPO	SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES		STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190			D1	6.86	8.00	0.270	0.315	3
A1	0.00	0.254	0.000	0.010			E	9.65	10.67	0.380	0.420	2, 3
b	0.51	0.99	0.020	0.039			E1	7.90	8.80	0.311	0.346	3
b1	0.51	0.89	0.020	0.035	4		е	2.54	BSC	0.100	BSC	
b2	1.14	1.78	0.045	0.070			Н	14.61	15.88	0.575	0.625	
b3	1.14	1.73	0.045	0.068	4		L	1.78	2.79	0.070	0.110	
С	0.38	0.74	0.015	0.029			L1	-	1.65	-	0.066	3
c1	0.38	0.58	0.015	0.023	4		L2	1.27	1.78	0.050	0.070	
c2	1.14	1.65	0.045	0.065			L3	0.25	BSC	0.010	BSC	
D	8.51	9.65	0.335	0.380	2		L4	4.78	5.28	0.188	0.208	

#### Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inches
- (7) Outline conforms to JEDEC® outline TO-263AB

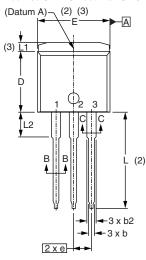
Revision: 13-Jul-17 Document Number: 96164

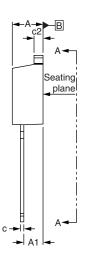


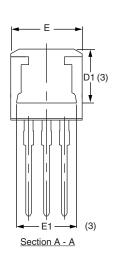
## **TO-262AA**

### **DIMENSIONS** in millimeters and inches

#### Modified JEDEC® outline TO-262







**⊕** 0.010 **M** A**M** B

#### Lead assignments

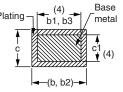


**Diodes** 

1. - Anode (two die)/open (one die)

2., 4. - Cathode

3. - Anode



Section B - B and C - C Scale: None

SYMBOL	MILLIN	IETERS	INC	INCHES			
J	MIN.	MAX.	MIN.	MAX.	NOTES		
Α	4.06	4.83	0.160	0.190			
A1	2.03	3.02	0.080	0.119			
b	0.51	0.99	0.020	0.039			
b1	0.51	0.89	0.020	0.035	4		
b2	1.14	1.78	0.045	0.070			
b3	1.14	1.73	0.045	0.068	4		
С	0.38	0.74	0.015	0.029			
c1	0.38	0.58	0.015	0.023	4		
c2	1.14	1.65	0.045	0.065			
D	8.51	9.65	0.335	0.380	2		
D1	6.86	8.00	0.270	0.315	3		
Е	9.65	10.67	0.380	0.420	2, 3		
E1	7.90	8.80	0.311	0.346	3		
е	2.54 BSC		0.100 BSC				
L	13.46	14.10	0.530	0.555			
L1	-	1.65	-	0.065	3		
L2	3.56	3.71	0.140	0.146			

#### **Notes**

(4) Dimension b1 and c1 apply to base metal only

Controlling dimension: inches

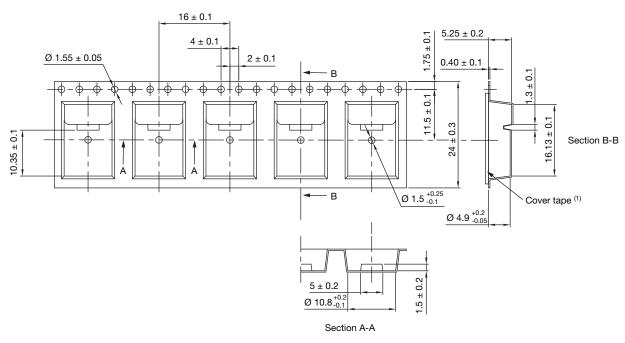
<sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994
(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

Thermal pad contour optional within dimension E, L1, D1 and E1

Outline conform to JEDEC® TO-262 except A1 (max.), b (min., max.), b1 (min.), b2 (max.), c (min.), c1(min.), c2 (max.), D (min.), E (max.), L1 (max.), L2 (min., max.)

# D<sup>2</sup>PAK (TO-263AB)

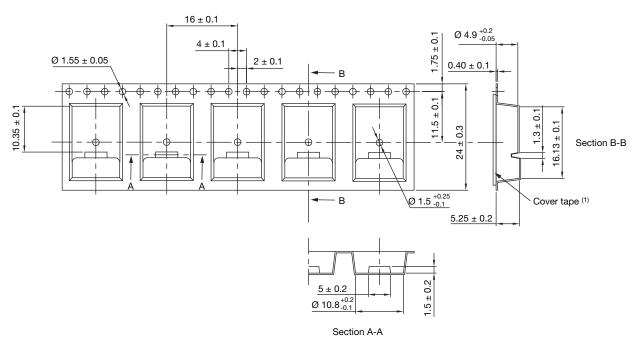
### **CARRIER TAPE FOR TAPE AND REEL LEFT** in millimeters



#### Note

(1) For dimensions, see next pages

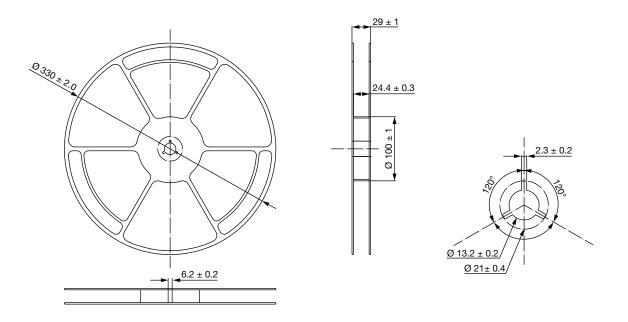
### **CARRIER TAPE FOR TAPE AND REEL RIGHT** in millimeters



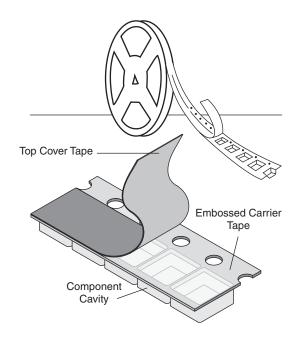
#### Note

(1) For dimensions, see next pages

### **REEL FOR CARRIER TAPE** in millimeters



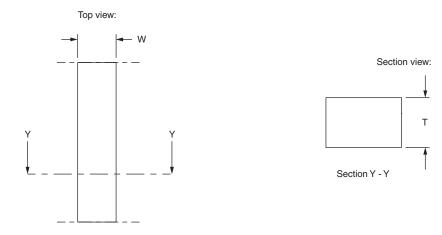
### CARRIER TAPE AND REEL PACKAGING D<sup>2</sup>PAK (TO-263AB)



# **Packaging Information**

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### **COVER TAPE FOR CARRIER TAPE** in millimeters



APPLICATION	COVER TAPE WIDTH W	COVER TAPE THICKNESS T	CARRIER TAPE WIDTH	MATERIAL
D <sup>2</sup> PAK (TO-263AB)	21.3 ± 0.1	0.060 ± 0.01	24	Antistatic/treated/transparent/polyester



## **Legal Disclaimer Notice**

Vishay

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